

650V 25A Field Stop Trench IGBT

V _{CES}	650V
I _{C(100°C)}	25A
V _{CE(sat) (Typ.)}	1.6V
P_D	174W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

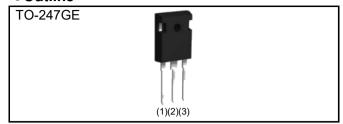
PFC

UPS

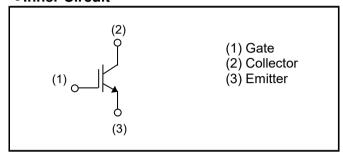
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Type	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	600
	Packing code	C13
	Marking	RGTH50TS65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit	
Collector - Emitter Voltage		V_{CES}	650	V	
Gate - Emitter Voltage		V_{GES}	±30	V	
Collector Current	T _C = 25°C	I _C	50	А	
	T _C = 100°C	I _C	25	Α	
Pulsed Collector Current		I _{CP} *1	100	А	
Power Dissipation	T _C = 25°C	P _D	174	W	
	T _C = 100°C	P _D	87	W	
Operating Junction Temperature		T _j	-40 to +175	°C	
Storage Temperature		T _{stg}	-55 to +175	°C	

^{*1} Pulse width limited by Timax.

●Thermal Resistance

Darameter	Symbol	Values			Unit
Parameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.86	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
r ai ai iletei			Min.	Тур.	Max.	UIIIL
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	ı	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	1	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V _{CE} = 5V, I _C = 17.5mA	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	$I_{C} = 25A, V_{GE} = 15V$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.6 2.1	2.1	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Darameter	Symbol	Conditions	Values			1.1
Parameter			Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1410	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	57	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	22	-	
Total Gate Charge	Q_g	V _{CE} = 300V	-	49	-	
Gate - Emitter Charge	Q_ge	I _C = 25A	-	15	-	nC
Gate - Collector Charge	Q _{gc}	V _{GE} = 15V	-	19	-	
Turn - on Delay Time	t _{d(on)}	I _C = 25A, V _{CC} = 400V	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	38	-	
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	94	-	ns
Fall Time	t _f	Inductive Load	-	50	-	
Turn - on Delay Time	t _{d(on)}	I _C = 25A, V _{CC} = 400V	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	38	-	
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	107	-	ns
Fall Time	t _f	Inductive Load	-	65	-	
		I _C = 100A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650V, V_{GE} = 15V$	FULL SQUARE			-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

• Electrical Characteristic Curves

Fig.1 Power Dissipation vs. Case Temperature

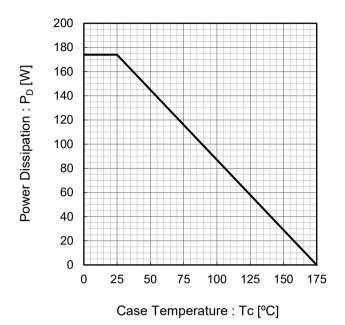


Fig.2 Collector Current vs. Case Temperature

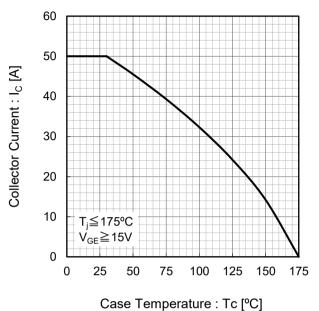
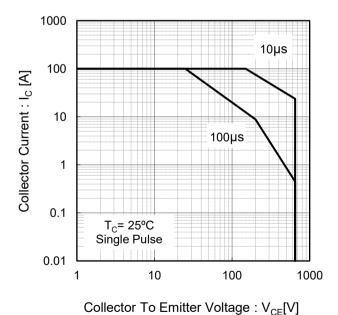


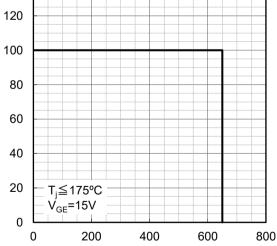
Fig.3 Forward Bias Safe Operating Area



Collector Current : $I_{\rm C}$ [A]

120

Fig.4 Reverse Bias Safe Operating Area



Collector To Emitter Voltage : $V_{CE}[V]$

•Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

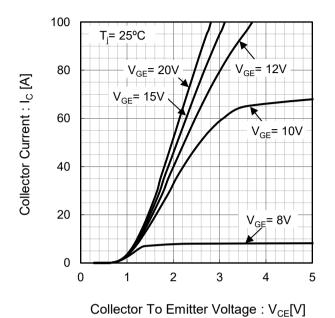
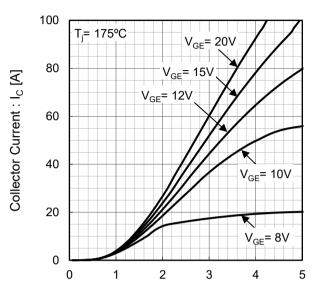


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V_{CE}[V]

Fig.7 Typical Transfer Characteristics

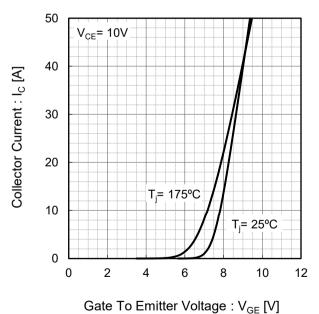
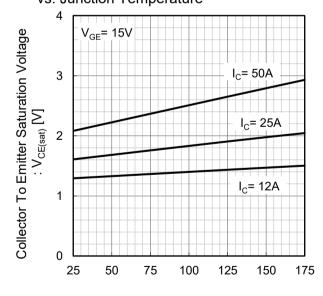


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

•Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

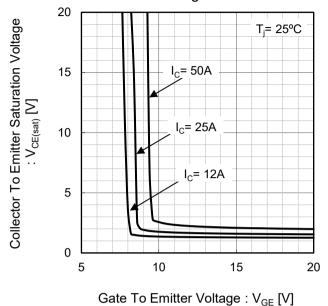
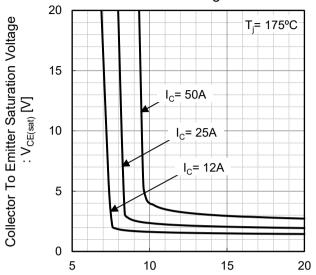


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage: V_{GE} [V]

Fig.11 Typical Switching Time vs. Collector Current

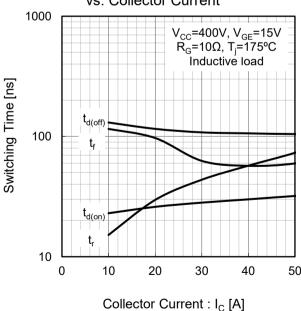
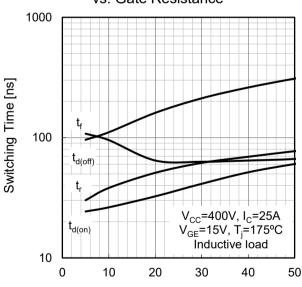


Fig.12 Typical Switching Time vs. Gate Resistance



•Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 $\mathsf{E}_{\mathsf{off}}$ Eor 0.1 V_{CC} =400V, V_{GE} =15V R_{G} =10 Ω , T_{j} =175°C Inductive load 0.01 0 10 20 30 40 50 Collector Current : I_C [A]

vs. Gate Resistance

10

See Solution

10 E_{off} E_{on} 10 $V_{cc}=400V, I_{c}=25A$ $V_{cg}=15V, T_{j}=175^{\circ}C$ Inductive load

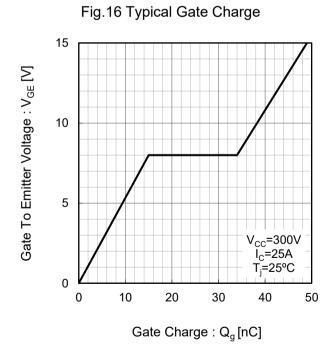
0.01

0 10 20 30 40 50

Gate Resistance : $R_{G}[\Omega]$

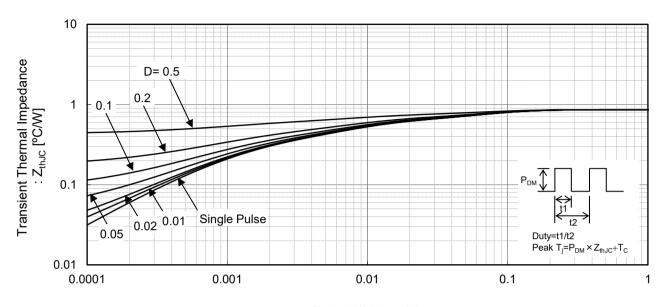
Fig.14 Typical Switching Energy Losses

Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 10 Cres f=1MHz V_{GE}=0V T_i=25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : $V_{CE}[V]$



• Electrical Characteristic Curves

Fig.17 IGBT Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

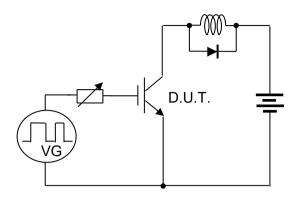


Fig.18 Inductive Load Circuit

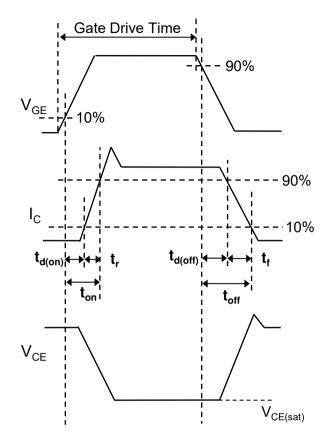


Fig.19 Inductive Load Waveform

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